

Roll No

EC-403**B.E. IV Semester**

Examination, December 2015

Digital Electronics**Time : Three Hours****Maximum Marks : 70**

- Note:** i) Answer five questions. In each question part A, B, C is compulsory and D part has internal choice.
- ii) All parts of each question are to be attempted at one place.
- iii) All questions carry equal marks, out of which part A and B (Max. 50 words) carry 2 marks, part C (Max. 100 words) carry 3 marks, part D (Max. 400 words) carry 7 marks.
- iv) Except numericals, Derivation, Design and Drawing etc.

UNIT - I

1. a) Convert the gray code 1011 to binary.
- b) Draw the diagram of AND gate and draw its truth table.
- c) Convert 1011101_2 to decimal.
- d) Explain Karnaugh's Map method with example.

OR

Define Demorgan's theorem in detail.

UNIT - II

2. a) Write the difference between Half adder and Full adder.
- b) Draw the diagram of BCD adder.
- c) What do you mean by universal gate? Explain in brief.
- d) Write short notes on:
 - i) FDM
 - ii) TDM.

OR

Draw the diagram of demultiplexer and explain its working.

UNIT - III

3. a) Draw the circuit diagram of 555 timer.
- b) Write the application of register.
- c) Distinguish between monostable, astable and bistable.
- d) Draw the circuit diagram of master Slave JK flip flop and explain its working.

OR

What do you mean by counter? Explain different types of counter in brief.

UNIT - IV

4. a) What do you mean by memory?
- b) Write the difference between RAM and ROM.
- c) What do you understand by PLA?
- d) Explain SRAM and DRAM in detail.

OR

Explain PROM, EPROM and EEPROM in detail.

UNIT - V

5. a) What do you mean by interfacing?
- b) What is ECL?
- c) Write the difference between NMOS and CMOS.
- d) Write short notes on :
 - i) RTL
 - ii) DTL

OR

Write short notes on :

- i) TTL
- ii) TIL
